

TOSHIBA TRANSISTOR SILICON NPN TRIPLE DIFFUSED TYPE

2SD553

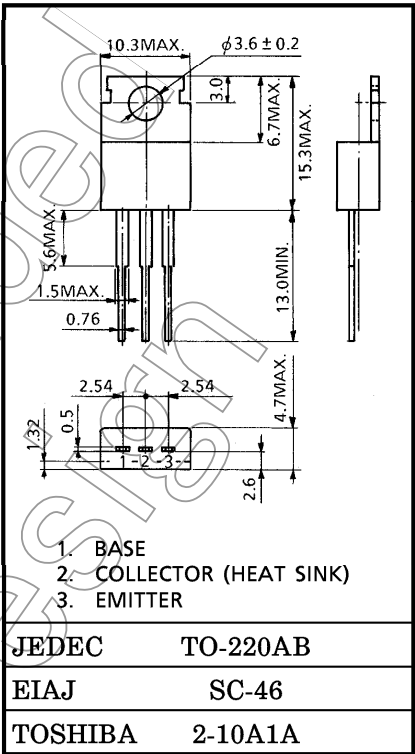
HIGH CURRENT SWITCHING APPLICATIONS

POWER AMPLIFIER APPLICATIONS

- Low Saturation Voltage :  $V_{CE(sat)}=0.4V$  (Max.) (at  $I_C=4A$ )
- Complementary to 2SB553.

INDUSTRIAL APPLICATIONS

Unit in mm



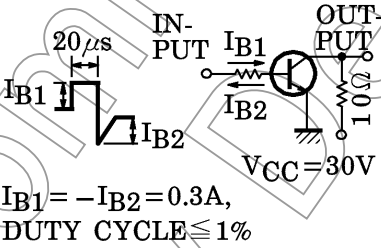
MAXIMUM RATINGS ( $T_a = 25^{\circ}C$ )

| CHARACTERISTIC              | SYMBOL              | RATING  | UNIT        |
|-----------------------------|---------------------|---------|-------------|
| Collector-Base Voltage      | $V_{CB0}$           | 70      | V           |
| Collector-Emitter Voltage   | $V_{CEO}$           | 50      | V           |
| Emitter-Base Voltage        | $V_{EBO}$           | 5       | V           |
| Collector Current           | $I_C$               | 7       | A           |
| Base Current                | $I_B$               | 1       | A           |
| Collector Power Dissipation | $T_a = 25^{\circ}C$ | 1.5     | W           |
|                             | $T_c = 25^{\circ}C$ | 40      |             |
| Junction Temperature        | $T_j$               | 150     | $^{\circ}C$ |
| Storage Temperature Range   | $T_{stg}$           | -55~150 | $^{\circ}C$ |

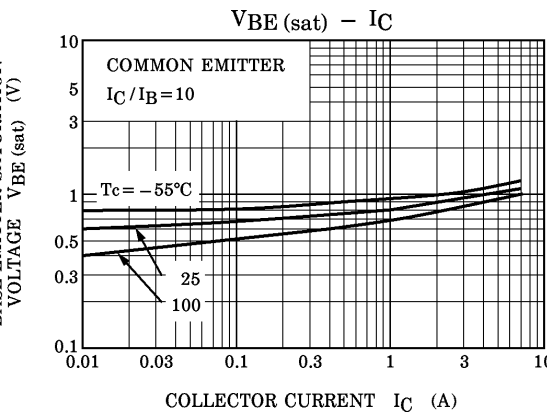
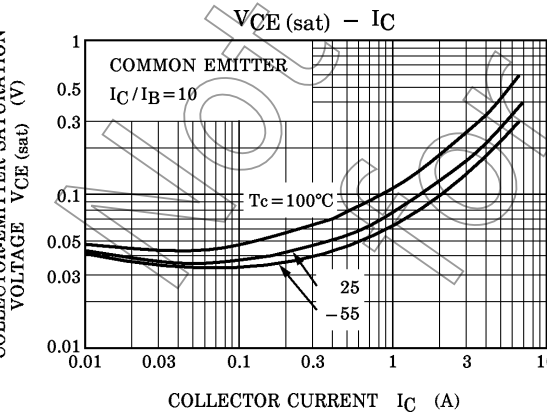
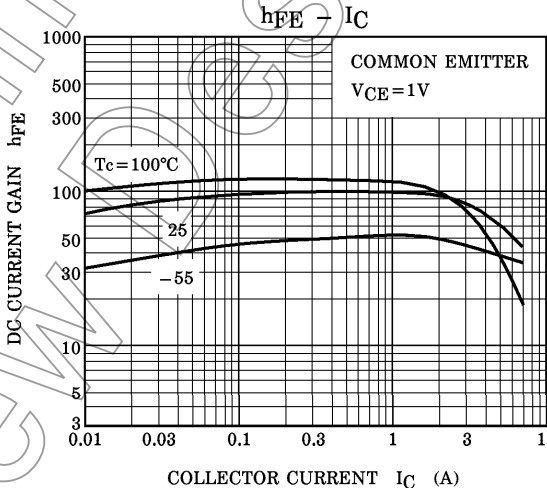
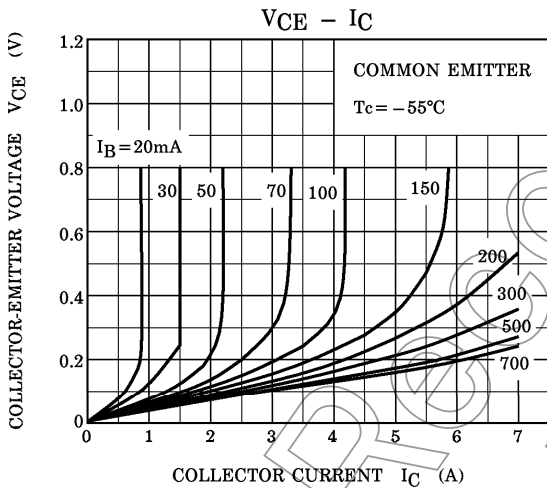
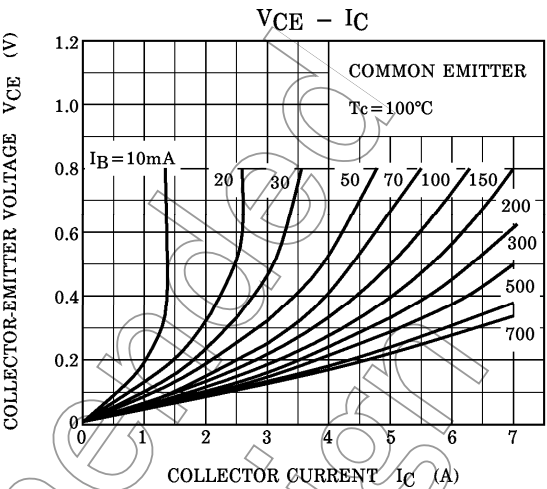
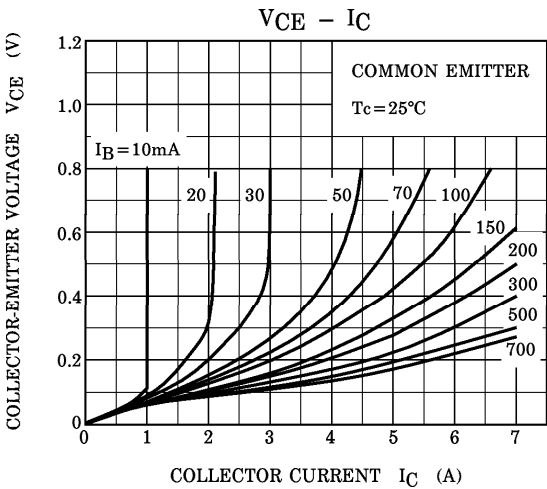
|         |          |
|---------|----------|
| JEDEC   | TO-220AB |
| EIAJ    | SC-46    |
| TOSHIBA | 2-10A1A  |

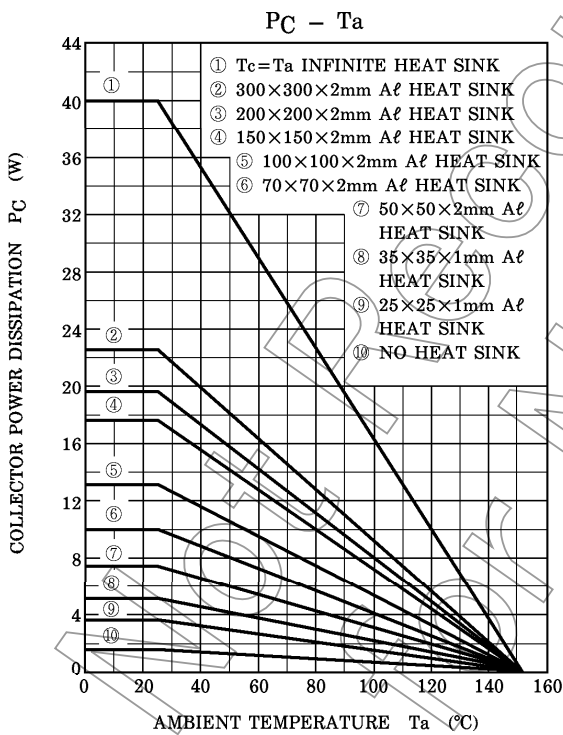
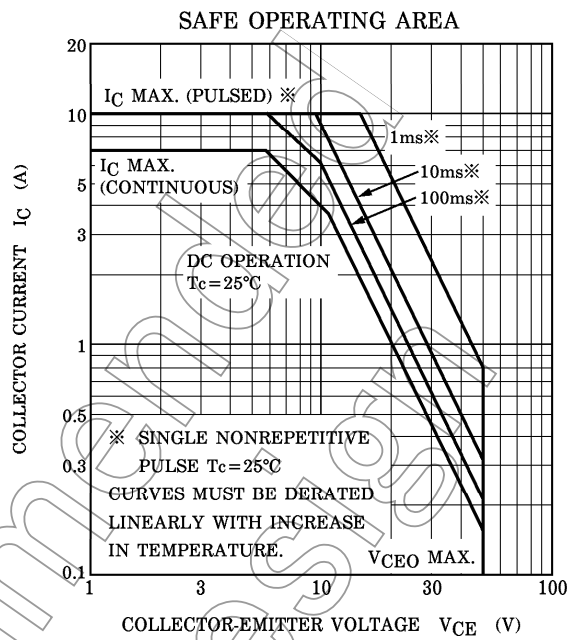
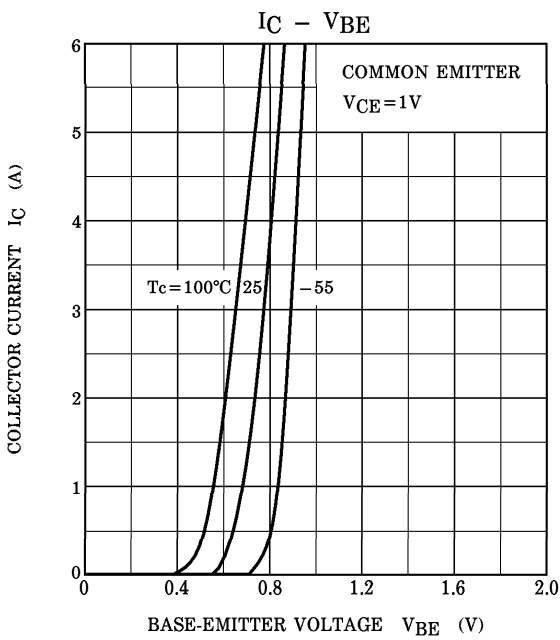
Weight : 1.9g  
Mounting Kit No. AC75

## ELECTRICAL CHARACTERISTICS (Ta = 25°C)

| CHARACTERISTIC                       |                       | SYMBOL        | TEST CONDITION                                                                                                                                                      | MIN. | TYP. | MAX. | UNIT    |
|--------------------------------------|-----------------------|---------------|---------------------------------------------------------------------------------------------------------------------------------------------------------------------|------|------|------|---------|
| Collector Cut-off Current            |                       | $I_{CBO}$     | $V_{CB} = 70V, I_E = 0$                                                                                                                                             | —    | —    | 30   | $\mu A$ |
| Emitter Cut-off Current              |                       | $I_{EBO}$     | $V_{EB} = 5V, I_C = 0$                                                                                                                                              | —    | —    | 50   | $\mu A$ |
| Collector-Emitter Breakdown Voltage  |                       | $V_{(BR)CEO}$ | $I_C = 50mA, I_B = 0$                                                                                                                                               | 50   | —    | —    | V       |
| DC Current Gain                      | $h_{FE(1)}$<br>(Note) |               | $V_{CE} = 1V, I_C = 1A$                                                                                                                                             | 70   | —    | 240  |         |
|                                      | $h_{FE(2)}$           |               | $V_{CE} = 1V, I_C = 4A$                                                                                                                                             | 30   | —    | —    |         |
| Collector-Emitter Saturation Voltage |                       | $V_{CE(sat)}$ | $I_C = 4A, I_B = 0.4A$                                                                                                                                              | —    | 0.2  | 0.4  | V       |
| Base-Emitter Saturation Voltage      |                       | $V_{BE(sat)}$ | $I_C = 4A, I_B = 0.4A$                                                                                                                                              | —    | 0.9  | 1.2  | V       |
| Transition Frequency                 |                       | $f_T$         | $V_{CE} = 4V, I_C = 1A$                                                                                                                                             | —    | 10   | —    | MHz     |
| Collector Output Capacitance         |                       | $C_{ob}$      | $V_{CB} = 10V, I_E = 0, f = 1MHz$                                                                                                                                   | —    | 250  | —    | pF      |
| Switching Time                       | Turn-on Time          | $t_{on}$      |  <p>IN-PUT <math>I_{B1}</math> <math>I_{B2}</math> <math>V_{CC} = 30V</math></p> | —    | 0.2  | —    | $\mu s$ |
|                                      | Storage Time          | $t_{stg}$     |                                                                                                                                                                     | —    | 2.5  | —    |         |
|                                      | Fall Time             | $t_f$         |                                                                                                                                                                     | —    | 0.5  | —    |         |

Note :  $h_{FE(1)}$  Classification O : 70~140, Y : 120~240





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